# Dual Complementary Pair Plus Inverter

The MC14007UB multipurpose device consists of three N–Channel and three P–Channel enhancement mode devices packaged to provide access to each device. These versatile parts are useful in inverter circuits, pulse–shapers, linear amplifiers, high input impedance amplifiers, threshold detectors, transmission gating, and functional gating.

#### Features

- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low–power TTL Loads or One Low–power Schottky TTL Load Over the Rated Temperature Range
- Pin-for-Pin Replacement for CD4007A or CD4007UB
- This device has 2 outputs without ESD Protection. Antistatic precautions must be taken.
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- This Device is Pb-Free and is RoHS Compliant

#### MAXIMUM RATINGS (Voltages Referenced to V<sub>SS</sub>)

Symbol	Parameter	Value	Unit
V <sub>DD</sub>	DC Supply Voltage Range	-0.5 to +18.0	V
V <sub>in</sub> , V <sub>out</sub>	Input or Output Voltage Range (DC or Transient)	–0.5 to V <sub>DD</sub> +0.5	V
I <sub>in</sub> , I <sub>out</sub>	Input or Output Current (DC or Transient) per Pin	±10	mA
P <sub>D</sub>	Power Dissipation, per Package (Note 1)	500	mW
T <sub>A</sub>	Ambient Temperature Range	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature Range	-65 to +150	°C
ΤL	Lead Temperature (8 second Soldering)	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Package: -7.0 mW/°C from 65°C 5o 125°C.



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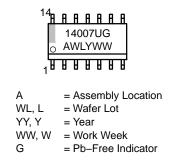


D SUFFIX CASE 751A

#### **PIN ASSIGNMENT**

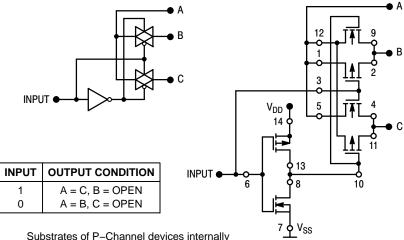
D-P <sub>B</sub>	1•	14	I V <sub>DD</sub>			
S–P <sub>B</sub> [	2	13	D-P <sub>A</sub>			
GATE <sub>B</sub>	3	12	] OUT <sub>C</sub>			
S–N <sub>B</sub> [	4	11	] S-P <sub>C</sub>			
D-N <sub>B</sub>	5	10	] GATE <sub>C</sub>			
GATE <sub>A</sub>	6	9	] S–N <sub>C</sub>			
v <sub>ss</sub> [	7	8	D–N <sub>A</sub>			
D = DRAIN						
S = SOURCE						

#### MARKING DIAGRAM

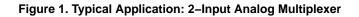


#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.



Substrates of P–Channel devices internally connected to  $V_{DD}$ ; substrates of N–Channel devices internally connected to  $V_{SS}$ .



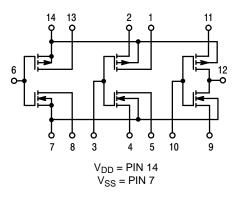


Figure 2. Schematic

				–55°C		25°C		125°C			
Symbol	Characteristic		V <sub>DD</sub> Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
V <sub>OL</sub>	Output Voltage V <sub>in</sub> = V <sub>DD</sub> or 0	"0" Level	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	Vdc
V <sub>OH</sub>	V <sub>in</sub> = 0 or V <sub>DD</sub>	"1" Level	5.0 10 15	4.95 9.95 14.95	- - -	4.95 9.95 14.95	5.0 10 15	- - -	4.95 9.95 14.95	- - -	Vdc
V <sub>IL</sub>	Input Voltage $(V_O = 4.5 \text{ Vdc})$ $(V_O = 9.0 \text{ Vdc})$ $(V_O = 13.5 \text{ Vdc})$	"0" Level	5.0 10 15	- - -	1.0 2.0 2.5	- - -	2.25 4.50 6.75	1.0 2.0 2.5		1.0 2.0 2.5	Vdc
VIH	$(V_O = 0.5 \text{ Vdc})$ $(V_O = 1.0 \text{ Vdc})$ $(V_O = 1.5 \text{ Vdc})$	"1" Level	5.0 10 15	4.0 8.0 12.5	- - -	4.0 8.0 12.5	2.75 5.50 8.25	- - -	4.0 8.0 12.5	- - -	Vdc
I <sub>OH</sub>	$\begin{array}{l} \text{Output Drive Current} \\ (\text{V}_{\text{OH}} = 2.5 \ \text{Vdc}) \\ (\text{V}_{\text{OH}} = 4.6 \ \text{Vdc}) \\ (\text{V}_{\text{OH}} = 9.5 \ \text{Vdc}) \\ (\text{V}_{\text{OH}} = 13.5 \ \text{Vdc}) \end{array}$	Source	5.0 5.0 10 15	-3.0 -0.64 -1.6 -4.2	- - -	-2.4 -0.51 -1.3 -3.4	-5.0 -1.0 -2.5 -10	- - -	-1.7 -0.36 -0.9 -2.4	- - -	mAdc
I <sub>OL</sub>	$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	5.0 10 15	0.64 1.6 4.2	- - -	0.51 1.3 3.4	1.0 2.5 10	- - -	0.36 0.9 2.4	- - -	mAdc
l <sub>in</sub>	Input Current		15	-	±0.1	-	±0.00001	±0.1	-	±1.0	μAdc
C <sub>in</sub>	Input Capacitance (V <sub>in</sub> = 0)		-	-	-	-	5.0	7.5	-	-	pF
I <sub>DD</sub>	Quiescent Current (Per Package)		5.0 10 15	- - -	0.25 0.5 1.0	- - -	0.0005 0.0010 0.0015	0.25 0.5 1.0	- - -	7.5 15 30	μAdc
Ι <sub>Τ</sub>	Total Supply Current (Notes (Dynamic plus Quiescer Per Gate) (C <sub>L</sub> = 50 pF)		5.0 10 15		•	I <sub>T</sub> = (1.	7 μA/kHz) f + 4 μA/kHz) f + 2 μA/kHz) f +	⊦ I <sub>DD</sub> /6	•		μAdc

#### ELECTRICAL CHARACTERISTICS (Voltages Referenced to V<sub>SS</sub>)

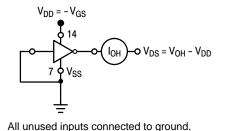
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
3. The formulas given are for the typical characteristics only at 25°C.
4. To calculate total supply current at loads other than 50 pF: I<sub>T</sub>(C<sub>L</sub>) = I<sub>T</sub>(50 pF) + (C<sub>L</sub> - 50) Vfk where: I<sub>T</sub> is in µA (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> - V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.003.

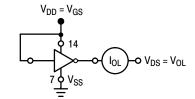
Symbol	Characteristic	V <sub>DD</sub> Vdc	Min	<b>Typ</b> (Note 6)	Max	Unit
t <sub>TLH</sub>	Output Rise Time $t_{TLH} = (1.2 \text{ ns/pF}) C_L + 30 \text{ ns}$ $t_{TLH} = (0.5 \text{ ns/pF}) C_L + 20 \text{ ns}$ $t_{TLH} = (0.4 \text{ ns/pF}) C_L + 15 \text{ ns}$	5.0 10 15	- - -	90 45 35	180 90 70	ns
t <sub>THL</sub>	Output Fall Time $t_{THL} = (1.2 \text{ ns/pF}) C_L + 15 \text{ ns}$ $t_{THL} = (0.5 \text{ ns/pF}) C_L + 15 \text{ ns}$ $t_{THL} = (0.4 \text{ ns/pF}) C_L + 10 \text{ ns}$	5.0 10 15	- - -	75 40 30	150 80 60	ns
t <sub>PLH</sub>	Turn–Off Delay Time $t_{PLH} = (1.5 \text{ ns/pF}) \text{ C}_L + 35 \text{ ns}$ $t_{PLH} = (0.2 \text{ ns/pF}) \text{ C}_L + 20 \text{ ns}$ $t_{PLH} = (0.15 \text{ ns/pF}) \text{ C}_L + 17.5 \text{ ns}$	5.0 10 15	- - -	60 30 25	125 75 55	ns
t <sub>PHL</sub>	Turn–On Delay Time $t_{PHL} = (1.0 \text{ ns/pF}) \text{ C}_{L} + 10 \text{ ns}$ $t_{PHL} = (0.3 \text{ ns/pF}) \text{ C}_{L} + 15 \text{ ns}$ $t_{PHL} = (0.2 \text{ ns/pF}) \text{ C}_{L} + 15 \text{ ns}$	5.0 10 15	- - -	60 30 25	125 75 55	ns

#### **SWITCHING CHARACTERISTICS** (Note 5) ( $C_L = 50 \text{ pF}, T_A = 25^{\circ}C$ )

5. The formulas given are for the typical characteristics only. Switching specifications are for device connected as an inverter.

6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.





All unused inputs connected to ground.

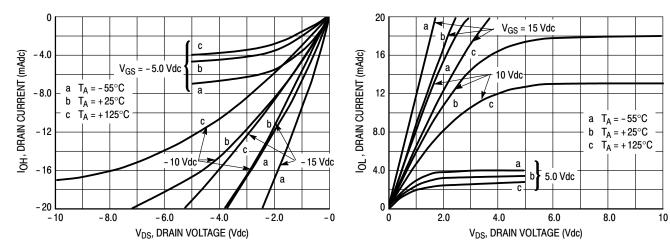


Figure 3. Typical Output Source Characteristics



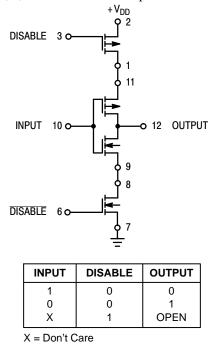
These typical curves are not guarantees, but are design aids. Caution: The maximum current rating is 10 mA per pin.

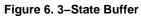


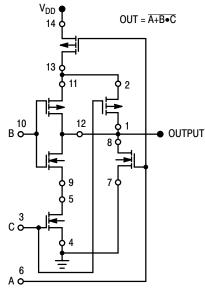
Figure 5. Switching Time and Power Dissipation Test Circuit and Waveforms

### APPLICATIONS

The MC14007UB dual pair plus inverter, which has access to all its elements offers a number of unique circuit applications. Figures 1, 6, and 7 are a few examples of the device flexibility.







Substrates of P–Channel devices internally connected to  $V_{DD}$ ; Substrates of N–Channel devices internally connected to  $V_{SS}$ .

Figure 7. AOI Functions Using Tree Logic

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC14007UBDG	SOIC-14 (Pb-Free)	55 Units / Rail
MC14007UBDR2G	SOIC-14 (Pb-Free)	2500 / Tape & Reel
NLV14007UBDR2G*	SOIC-14 (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
 \*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP

Capable.

# DUSEU

0.068

0.019

0.344

0.244



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

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#### DATE 03 FEB 2016

STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 2: CANCELLED	STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE	STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE
STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE	STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE	STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE	STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE

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